# Vishay Sfernice



# **Single Value Chip Resistors**



#### Actual Size

The demand for high precision, high stability resistive chips for incorporating in hybrid micro-circuits has increased and is catered for by the comprehensive range of VISHAY micro and minichips.

The super stable RMK nickel chromium resistive film has transformed the performances and characteristics of micro resistive chips bringing a "new state-of-the-art" to the technology. A variety of substrates are available in silicon, alumina, to ensure the best possible characteristics compatible with your application needs.

Precision wafer laser trimming is employed to trim each resistor to precise tolerance.

#### **FEATURES**

- Precise tolerance from  $\pm$  0.01 % to  $\pm$  1 %
- Wide resistance ranges from 1 k $\Omega$  to 2 M $\Omega$
- Low temperature coefficient ± 10 ppm/°C max.
- Excellent stability < 500 ppm (2000 h, at + 70 °C under Pn)
- Wirebondable



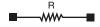




#### **TYPICAL PERFORMANCE**

	ABS
TCR	5 ppm/°C
TOL.	0.01 %

#### **SCHEMATIC AND PATTERN**



STANDARD ELECTRICAL SPECIFICATIONS		
TEST	SPECIFICATIONS	CONDITIONS
MATERIAL	ULTRAFILM <sup>®</sup>	
Resistance range	1 kΩ to 750 kΩ RMK 55 1 kΩ to 2 MΩ RMK 515	
Absolute TCR:	± 5 ppm/°C ± 10 ppm/°C	0 to + 70 °C - 55 °C to + 155 °C
Absolute tolerance:	0.01 % to 1 %	
Stability: ∆R/R	± 0.03 %	2000 h Pn at + 70 °C
Voltage coefficient	< 0.1 ppm/V	
Working voltage	100 V	
Operating temperature range	- 55 °C to + 155 °C <sup>(1)</sup>	
Storage temperature range	- 55 °C to + 155 °C	
Noise	< - 35 dB typical	
Thermal EMF	< 0.01 μV/°C	
Shelf life stability	50 ppm	1 year at + 25 °C
Power rating	250 mW (RMK 55)/500 mW (RMK515) 125 mW (RMK 55)/250 mW (RMK 515)	25 °C 70 °C

#### Note

<sup>(1)</sup> For temperature up to 200 °C, please contact factory

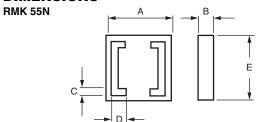
<sup>\*</sup> Please see document "Vishay Green and Halogen-Free Definitions (5-2008)" http://www.vishay.com/doc?99902

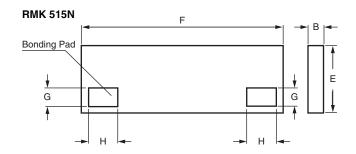


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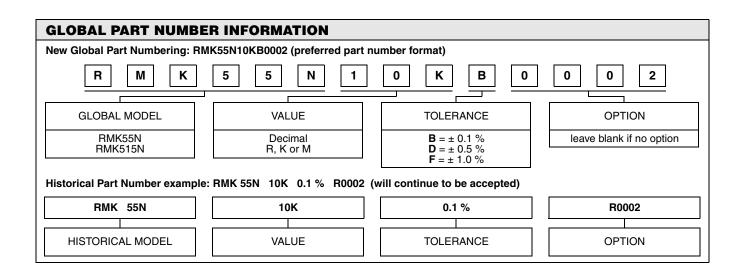
### **DIMENSIONS**





DIMENSION	INCHES	MILLIMETERS
Α	0.050	1.27
В	0.015 maximum	0.4 maximum
С	0.005	0.12
D	0.010	0.27
Е	0.050	1.27
F	0.150	3.81
G	0.015	0.40
Н	0.023	0.60

MECHANICAL SPECIFICATIONS		
Resistive element	Nichrome	
Passivation	Silicon Nitride	
Substrate material	Silicon	
Bonding pads	Aluminum	





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